Toshiba Intelligent Power Device Silicon Monolithic Power MOS Integrated Circuit

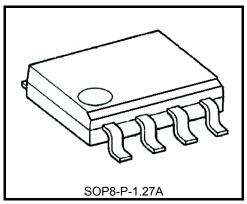
TPD1039F

Low-Side Power Switch for Motor, Solenoid and Lamp Drivers

The TPD1039F is a monolithic power IC intended for low-side load switching applications. The output has a vertical MOSFET, and the input can be directly driven from CMOS or TTL logic (e.g., an MPU). The TPD1039F provides intelligent protection functions.

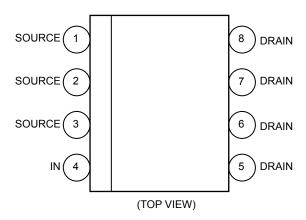
Features

- A structure that incorporates control circuitry and a vertical power MOSFET on a single chip.
- Can be directly driven from a microprocessor, a CMOS logic IC, etc.
- Overvoltage, overtemperature and overcurrent protections
- Low ON-resistance: RDS (ON) = 0.25Ω (max) (@VIN = 5 V, ID = 1 A, Tch = 25°C)
- Housed in the 8-pin SOP package and supplied in embossed carrier tape.

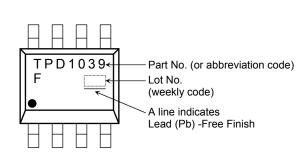


Weight: 0.08 g (typ.)

Pin Assignment (top view)

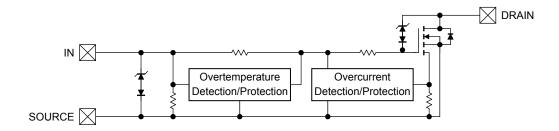


Marking



Note: This product has a MOS structure and is sensitive to electrostatic discharge.

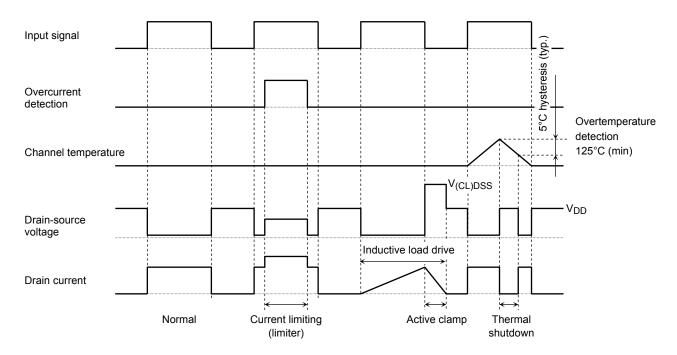
Block Diagram



Pin Description

Pin No.	Symbol	Pin Description
1, 2, 3	SOURCE	Source (ground) pins.
4	IN	Input pin. This pin is connected to a pull-down resistor internally, so that even if the input is open-circuited, the output never turns on inadvertently.
5 ,6, 7, 8	DRAIN	Drain pins. The output current is limited to 5 A (typ.) even if an excessive current flows into a device due to an in-rush current of a lamp or load short-circuit.

Timing Chart



2

Truth Table

V _{IN}	V_{DS}	Output State	Operating State		
L	Н	Off	Normal		
Н	L	On	Nomiai		
L	Н	Off	Load short-circuited		
Н	Н	Current limiting(limiter)	Load Short-circuited		
L	Н	Off	Overtemperature		
Н	Н	Off	Overlemperature		

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V _{DS} (DC)	45	V
Drain current	I _D (DC)	1.5	А
Input voltage	V _{IN}	−0.5 to 6	V
Power dissipation (Note 2-a)	P _{D(1)}	1.1	W
Power dissipation (Note 2-b)	P _{D(2)}	0.425	W
Single pulse active clamp capability (Note 3)	E _{AS}	20	mJ
Active clamp current	I _{AR}	1.5	Α
Repetitive active clamp capability (Note 2-a) (Note 4)	E _{AR}	0.11	mJ
Operating temperature	T _{opr}	-40 to 85	°C
Channel temperature	T _{ch}	150 (Note 5)	°C
Storage temperature	T _{stg}	–55 to 150	°C

Note 1: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

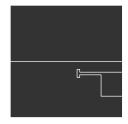
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

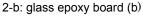
Characteristics	Symbol	Rating	Unit
The second are interested as a selection of	Du ()	113.5 (Note 2-a)	°C /W
Thermal resistance, channel to ambient	R _{th(ch-a)}	294.0 (Note 2-b)	C / VV

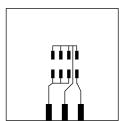
Note 2:

2-a: glass epoxy board (a)



FR-4 25.4 × 25.4 × 0.8 (unit: mm)





FR-4 25.4 × 25.4 × 0.8 (unit: mm)

Note 3: Active clamp capability (single pulse) test condition V_{DD} = 25 V, T_{ch} = 25 °C (initial), L = 10 mH, I_{AR} = 1.5 A, R_G = 25 Ω

Note 4: Repetitive rating: Pulse width limited by maximum channel temperature

Note 5: Overtemperature protection is tripped at a channel temperature of 125°C.

Ensure that the channel temperature, Tch, does not exceed 125°C under the worst-case conditions.

Electrical Characteristics (Tch = 25°C)

Characteristics	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Drain-source clamp voltage	V (CL)DSS	-	$V_{IN} = 0 \text{ V}, I_D = 1 \text{ mA}$	45	-	-	V
High-level input voltage	V _{IH}	1	$V_{DS} = 10 \text{ to } 40 \text{ V}, I_D \ge 1 \text{ A}$	3.5	-	6	V
Low-level input voltage	V _{IL}	1	1 $V_{DS} = 10 \text{ to } 40 \text{ V}, I_D \le 10 \mu\text{A}$		-	0.8	V
Drain cut-off current	I _{DSS}	-	V _{IN} = 0 V, V _{DS} = 40 V	-	-	10	μА
High-level input current	liH	-	V _{IN} = 5 V, at normal operation		-	400	μА
Drain-source ON-resistance	R _{DS(ON)}	-	V _{IN} = 5 V, I _D = 1 A	-	-	0.25	Ω
Protective circuit operation input Voltage range	V _{IN(opr)}	-	-	3.5	-	6	V
Overtemperature detection (Note 6)	T _{OT}	2	V _{IN} = 5 V, V _{DD} = 12 V	125	-	-	°C
Overcurrent detection	loc	3	V _{IN} = 5 V, V _{DS} = 24 V	-	5	-	Α
Cuitabina timoo	t _{on}	4	$V_{DD} = 24 \text{ V}, V_{IN} = 0 \text{ V/5 V},$	-	15	-	0
Switching times	t _{off}		$R_L = 24\Omega$	-	45	-	μS
Drain-source diode forward Voltage	V _{DSF}	-	V _{IN} = 0 V, I _{DR} = 1.5 A	-	0.9	1.8	V

Note 6: Overtemperature protection is tripped at a channel temperature of 125°C.

Ensure that the channel temperature, Tch, does not exceed 125°C under the worst-case conditions.

This feature is intended to protect the device against damage. The device reliability is not guaranteed if the device persists to remain overtemperature protection mode.

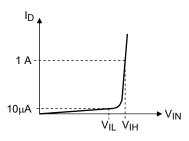
Test Circuit 1

H-level input voltage, L-level input voltage measuring circuit

Test circuit

DRAIN TPD1039F V_{IN} SOURCE V_{IN} V_{IN}

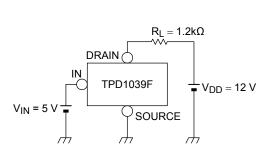
Measured waveforms



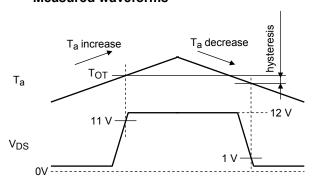
Test Circuit 2

Overtemperature detection measuring circuit

Test circuit



Measured waveforms

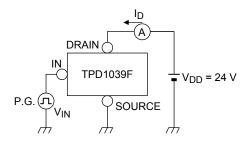




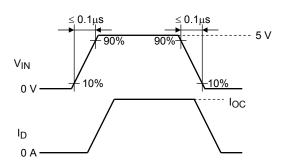
Test Circuit 3

Overcurrent detection circuit

Test circuit



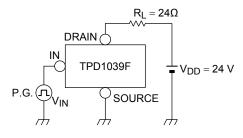
Measured waveforms



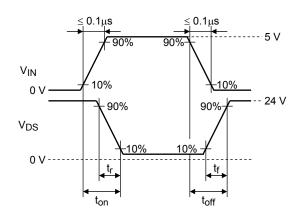
Test Circuit 4

Switching time measuring circuit

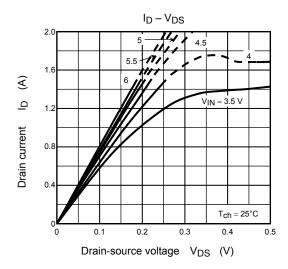
Test circuit

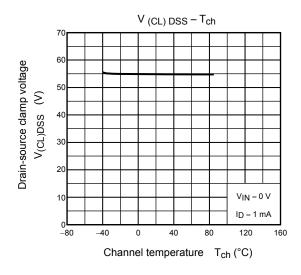


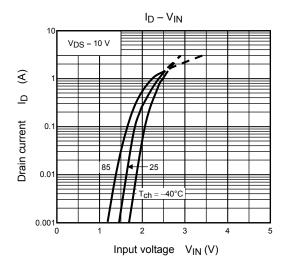
Measured waveforms

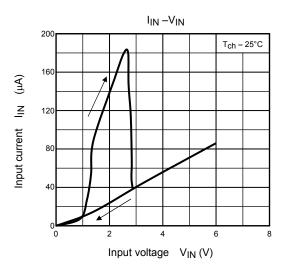


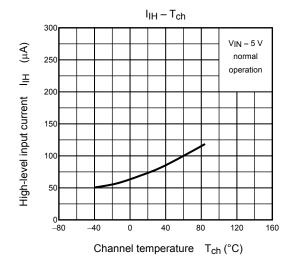
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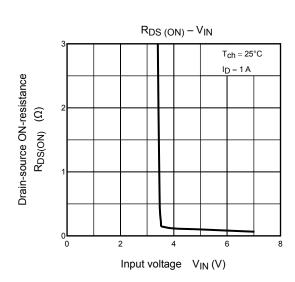




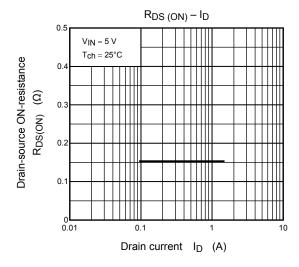


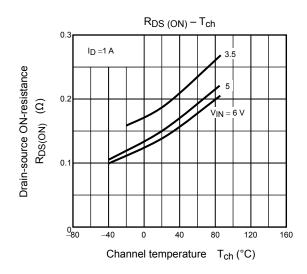


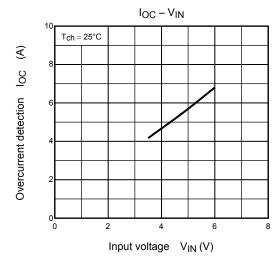


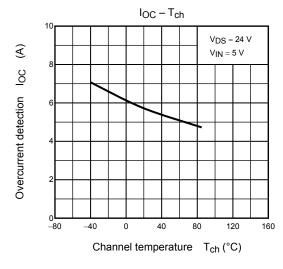


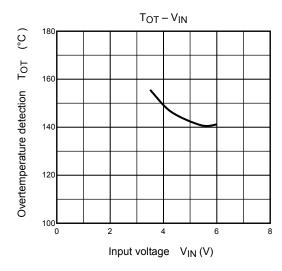
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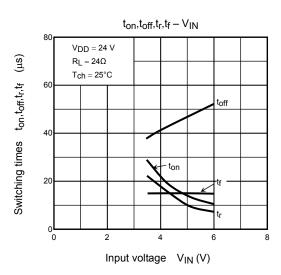


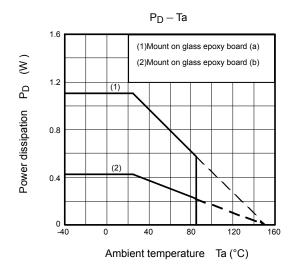


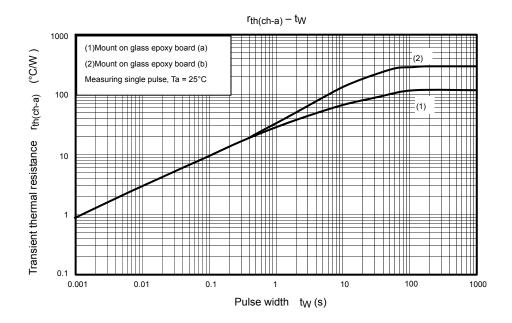




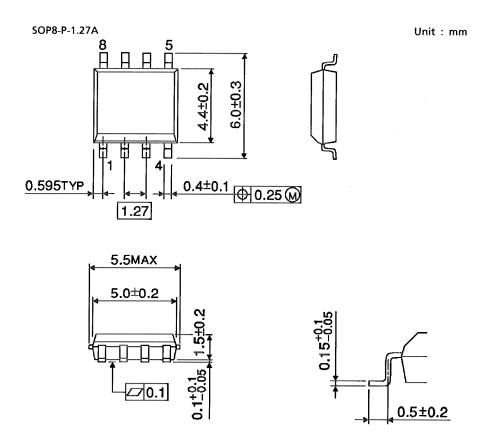








Package Dimensions



Weight: 0.08 g (typ.)

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20070701-EN GENERAL

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